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TNFORMATION DISCLOSURE STATEMENT BY APPLICANT

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of

Complete if Known

Application Number 10/666,482

Filing Date September 18, 2003

First Named Inventor Koji Yamada

Art Unit 2883

Examiner Name FRIN CHIEM

Attomey Docket Number 96790P442

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Examiner Initials*	Cite No.1	Document Number Number - Kind Code ² (if known)	Publication Date or Issue Date MM-DD-YYYY	Name of Patantee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear				
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*Examin ar., Initial if reference considered, whether or not citation is in conformance with MPEP 609. Drew tine through citation if not in conformance and not considered. Include copy of this form with next communication.

¹Applicant's unique distion designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English, larguage Translation is attached.

Based on PTO/SE/05A (08-03) as modified by Blakely, Solokoff, Taylor & Zafman (wir) 08/11/2003.

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)			Application Number	10/666,482		
			Filing Date	September 18, 2003		
			First Named Inventor	Koji Yamada		
			Art Unit	4883		
(430 63 111411)	7 3/10013 03 /1000330/7/		Examiner Name	ERIN CHIEM		
Sheet	of		Attorney Docket Number	06700P442		

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Substitute for form	1449A&B/PTO	Application Number	10/666 48 2
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STATEMENT BY	APPLICANT	First Named Inventor	KOTI, YAMADA
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